

SANYO Semiconductors DATA SHEET

Bi-CMOS IC

LV5803M — Step-down Switching Regulator

Overview

LV5803M is a 1ch step-down switching regulator. 0.2Ω FET is incorporated on the upper side to achieve high-efficiency operation for large output current. Low-heat resistance and compact-package MFP8 employed. Current mode control type, with superior load current response and easy phase compensation ON/OFF pin, allowing the standby mode with the current drain of 80μ A or less Pulse-by-pulse over-current protection and overheat protection available for protection of load devices Soft start pin to be provided with a capacitance for soft start.

Functions

- 2A 1ch step-down switching regulator
- Wide input dynamic range (4.5 to 18V)
- High efficiency (90% $I_{OUT} = 1A$, $V_{IN} = 12V$, $V_{O} = 5V$)
- Standby mode
- Over-current protection

• Thermal shutdown

Reference voltage: 0.8VFixed frequency: 330kHz

• Soft start

• Compact package: MFP8 (225mil)

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum input V _{IN} voltage	V _{IN} max		20	V
BOOT pin maximum voltage	V _{BT} max		25	V
SW pin maximum voltage	V _{SW} max		V _{IN} max	V
BOOT pin-SW pin maximum voltage	V _{BS-SW} max		7	V
EN pin maximum voltage	V _{EN max}		20	V
FB, COMP, SS pin maximum voltage	Vfs max		7	V
Allowable power dissipation	Pd max	With specified substrate *	1.15	W
Junction temperature	Tj max		150	°C
Operating temperature	Topr		-20 to 80	°C
Storage temperature	Tstg		-40 to 150	°C

^{*} Specified substrate: $46.4 mm \times 31.8 mm \times 1.7 mm$, glass epoxy substrate

Note: Plan the maximum voltage while including coil and surge voltages, so that the maximum voltage is not exceeded even for an instant.

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LV5803M

Recommended Operating Conditions at Ta = 25°C

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Parameter	Symbol	Conditions	Ratings	Unit
V _{IN} pin voltage	V _{IN}		4.5 to 18	V
BOOT pin voltage	V _{BT}		-0.3 to 23	V
SW pin voltage	V _{SW}		-0.4 to V _{IN}	V
BOOT pin-SW pin maximum voltage	V _{BS-SW}		6.5	V
EN pin maximum voltage	V _{EN}		18	٧
FB, COMP, SS pin voltage	V _{FSO}		6	V

Electrical Characteristics at Ta = 25 °C, $V_{\mbox{IN}} = 12 \mbox{V}$, unless otherwise specified.

D	0	0 11	Ratings			
Parameter	Symbol	Conditions	min	typ	max	Unit
IC current drain at standby	I _{CC} 1	EN=0V		80		μА
IC current drain in operation	I _{CC} 2	EN=open		2		mA
Efficiency	Effcy	V _{IN} =12V, I _{OUT} =1A, Vo=5V, Design target *1		90		%
Reference voltage	Vref	V _{IN} =4.5V to 18V (±2%)	-2%	0.8	+2%	V
FB pin bias current	Iref	FB=0.8V application		10	100	nA
High-side ON resistance	RonH	BOOT=5V		0.20		Ω
Oscillation frequency	fosc		265	330	395	kHz
Oscillation frequency during short-circuit protection	foscs		26	33	40	kHz
EN high-threshold voltage	Venh		1.25	1.55	1.85	V
EN low-threshold voltage	VenI		0.95	1.25	1.55	V
EN pull-up current	len	EN=0V		45		μА
Maximum ON DUTY	D max			86		%
Current limit peak value 1	lc1	V _{IN} =12V, V _{OUT} =5V, L=10μH	2.5		5.3	Α
Current limit peak value 2	lc2	V _{IN} =12V, V _{OUT} =3.3V, L=10μH	2.8		5.6	Α
Current limit peak value 3	lc3	V _{IN} =12V, V _{OUT} =1.2V, L=10μH	3.1		5.9	Α
Thermal shutdown temperature	Ttsd	*Design guarantee *2		160		°C
Thermal shutdown temperature hysteresis	Dtsd	*Design guarantee *2	_	40		°C
Soft start current	ISS	SS=0V	6	10	14	μΑ

^{*1:} Reference value (not tested before shipment)

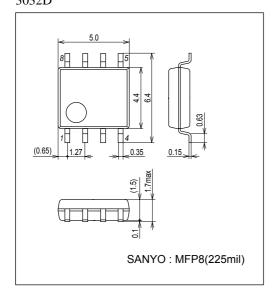
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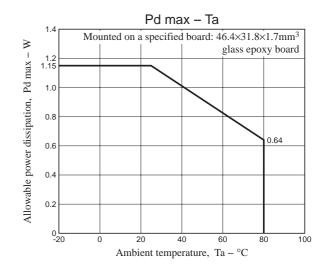
^{*2:} Design guarantee (value guaranteed by design and not tested before shipment)

Package Dimensions

unit: mm (typ)

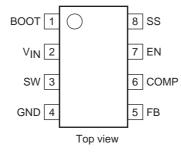
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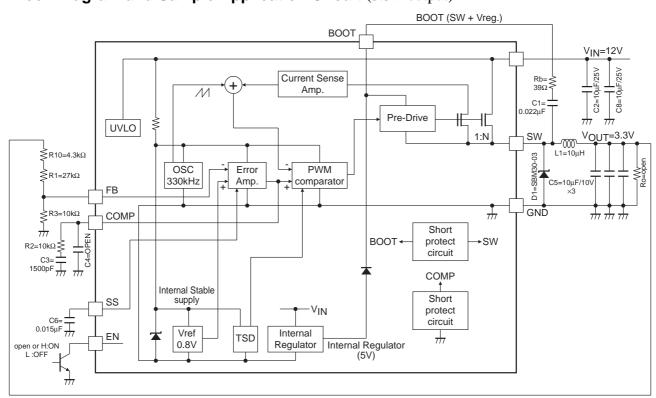


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Pin Assignment



Block Diagram and Sample Application Circuit (3.3V output)



- C1, C8, C5 = ceramic capacitor used.
- L1 = CDRH105RPN-100NC (sumida made)

Pin Fi	unction		
Pin No.	Pin name	Function	www.DataSheet4Ll.com Equivalent circuit
1	BOOT	Upper MOS transistor boot strap capacitance connection	4
		pin. Connect the boot capacitance of about $0.022\mu F$ between SW pins.	
		To protect the SW pin's absolute maximum rating, to ensure stable operation, and to eliminate noise, the boot	Short protection circuit BOOT
		capacitance serial resistance (about 100Ω) Rb proves effective.	
2	V _{IN}	Input voltage pin. Connect substantially large (10µF 2 parameters or more) capacitance between this pin and GND.	Output MOS
3	SW	Power switch pin. Connect the output LC filter. Connect the above capacitance between this pin and BOOT pin.	sw
4	GND	Ground pin.	
5	FB	Feedback pin. Sets the output voltage by means of split resistor in the section of the output voltage V_{OUT} - FB - GND. V_{OUT} setting is made as calculated below: $V_{OUT} = Vref \times \{1 + \frac{(R1 + R10)}{R3}\}$ $Vref = 0.8V$ Example: 3.3V output voltage (See Block Diagram and Sample Application Circuit) $V_{OUT} = Vref \times \{1 + \frac{(27k + 4.3k)}{10k}\}$ = 3.304V	VIN Internal regulation line
8	SS	Soft start pin. Sets the soft start time by means of the built-in $10\mu A$ source voltage and external soft start capacity. The soft start capacity C6 can be set as follows: $C6 = 10\mu A \times \frac{Tss}{Vref}$ Where, Tss is the soft start time and Vref is the reference voltage. $Example: 1.2ms \ soft \ start \ time \ achieved$ $C6 = 10\mu A \times \frac{1.2ms}{0.8V} = 0.015\mu F$	SS W FB
6	COMP	Phase compensation pin. Connects with the phase compensation external capacitance and resistance of DC/DC converter close loop.	Internal regulation line Short protection circuit COMP
7	EN	Enable pin. Converter enabled when set to the HIGH voltage or OPEN state and disabled when connected to GND.	VIN 5μΑ EN 93kΩ Q117 93kΩ Q117

Considerations for the design

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- During use with V_{IN} = 12V or less, the boot strap voltage may become deficient due to intermittent operation at no load, resulting in failure of normal operation. In this case, insert a resistance of about 500 Ω between V_{OUT} and GND and avoid the intermittent operation mode during use.
- Insertion of serial beads in the Schottky diode for removal of noise may cause generation of the negative voltage deviating from the absolute maximum rating at the SW pin, resulting in failure of normal operation. In such an event, do not insert beads as above described and, instead, remove noise by means of the BOOT resistance Rb.

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